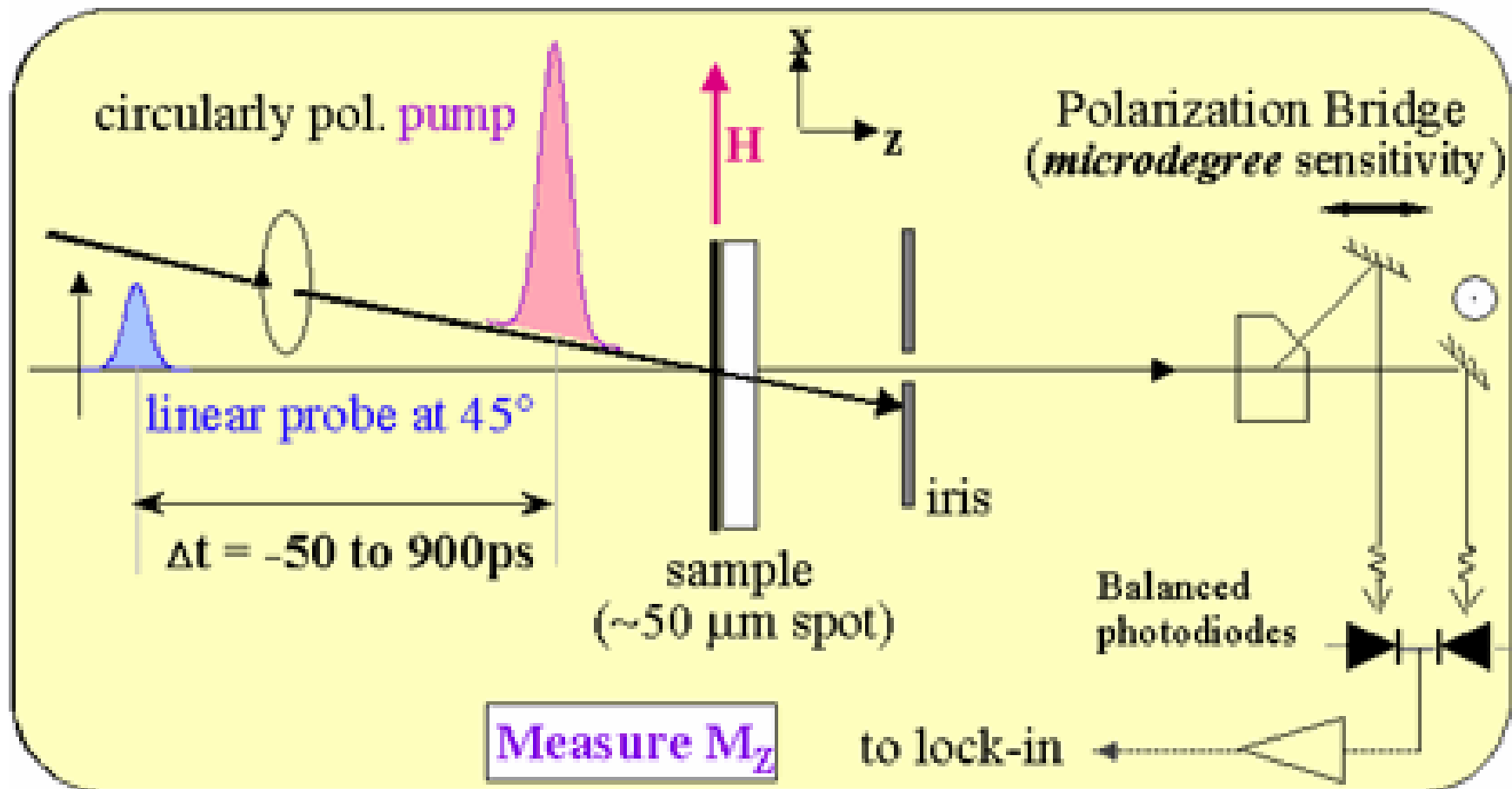


# Cathode R&D

- Faraday Rotation experiment plans

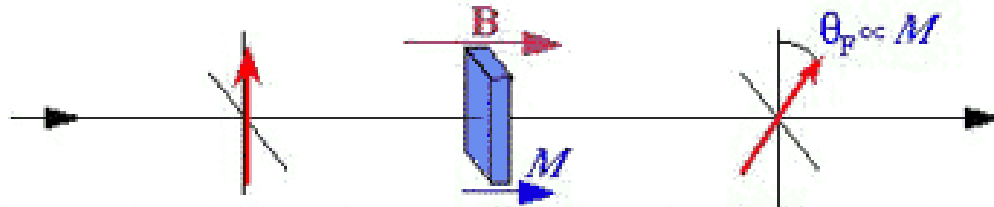
# Faraday Rotation

- Polarization measurements without the NEA effects
- Study of the structures
- Independent measurements of left – right asymmetry
- Very high resolution polarization measurement



# Basic principle

- **Faraday Effect** : Rotation of polarization upon transmission through magneto-birefringent media.



- **Rotation angle  $\theta_F$**  directly proportional to the **difference** in index of refraction for RCP and LCP light,  $(\eta_+ - \eta_-) \propto M$ .

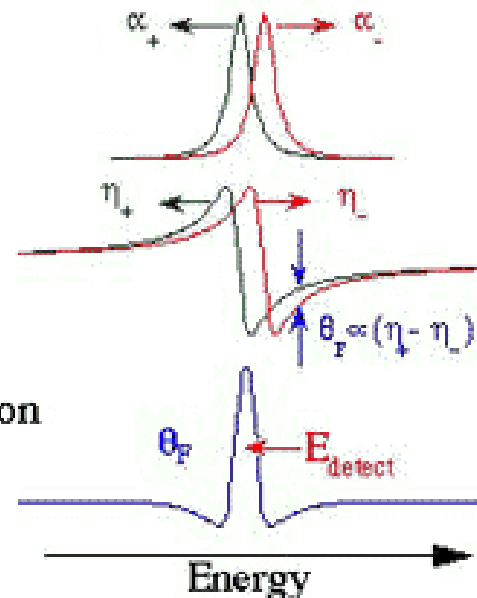
- **Near quantum-well resonance:**

- Zeeman-split absorption peaks

- Associated indices of refraction

- Resultant resonant Faraday rotation

$$\theta_F(\omega) = \frac{\omega L_{\text{eff}}}{2c} (\eta_+ - \eta_-)$$



$$\theta_1 / \theta_2 \propto P_1 / P_2$$

# What can we measure?

- Measure spin coherence evolution with time
- Relative values of polarization of different samples
- Right-left hand polarization asymmetry
- With different probe wavelengths we can measure depolarization effects as a function of energy

# Working out the numbers

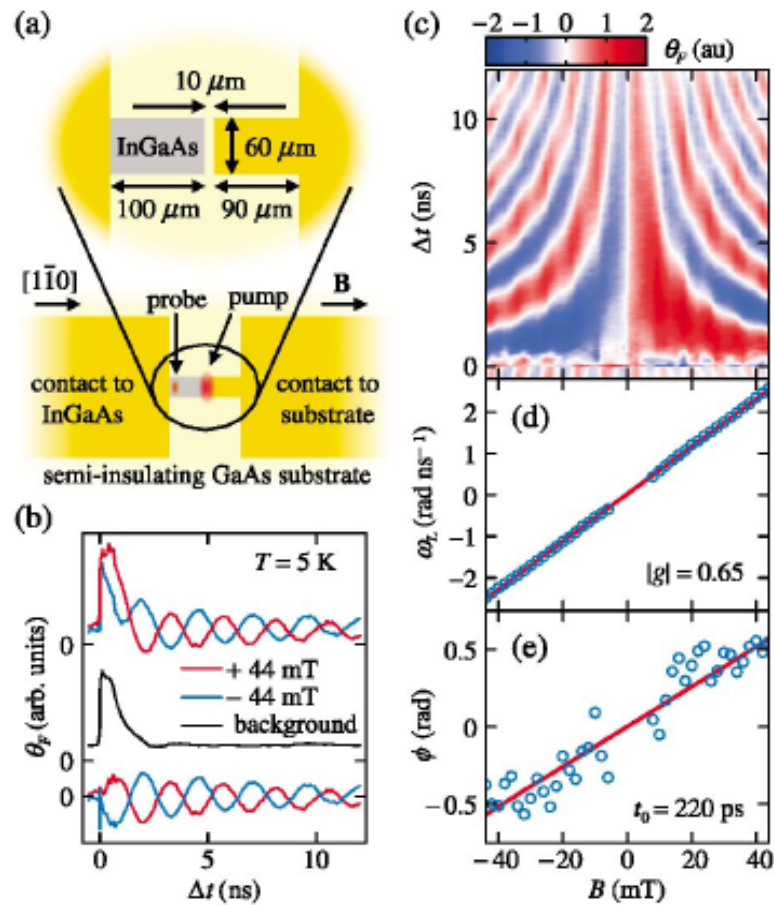


FIG. 4 (color). (a) Device schematic. (b) Time evolution of voltage-induced  $\theta_F$ . Top curves (red,  $B = +44$  mT, blue,  $B = -44$  mT) show the raw data. Black curve is the background signal. Bottom curves show the data after background subtraction. (c)  $\theta_F$  (background subtracted) as a function of  $\Delta t$  and  $B$ . (d) and (e) show  $\omega_L$  and  $\phi$ , respectively, obtained from fits to data in (c).

- Spot size :  $\sim 100\mu\text{m}$
- Pump power :  $\sim 20\mu\text{W}$
- Probe power:  $\sim 5\mu\text{W}$
- Expected theta

$$\theta = 2\pi A d \rho_{el} I_{pr} \sigma_x \sigma_y$$

$$\rho_{el} \sim 8\mu\text{m}^{-3}$$

# Plans

## Equipment

- Readout system already available
- TiSapphire modelocked laser ordered by U. of Wisconsin
- Where we put the Ti sapphire laser
- Which pump laser we use
- Other..

1. Saxet new sample arriving today (thin GaAs layer with thick W lines on top)

2. Collaboration with U. of New Mexico for samples growth